

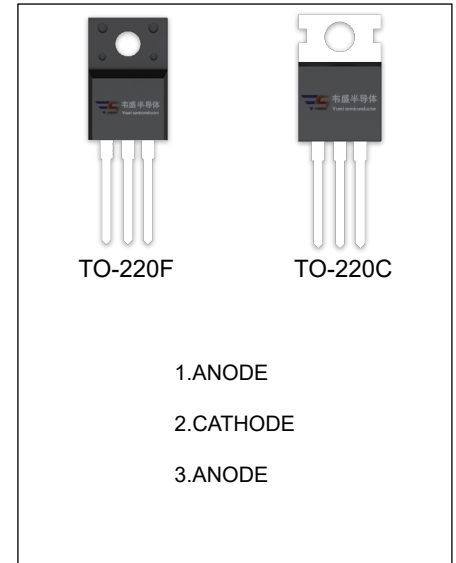
SBD30200CT、SBDF30200CT SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_O	30 (2×15) A
V_{RRM}	200 V
T_j	150 °C
$V_{F(typ)}$	0.75V (@T_j=125°C)

FEATURES

- Low Power Loss,High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



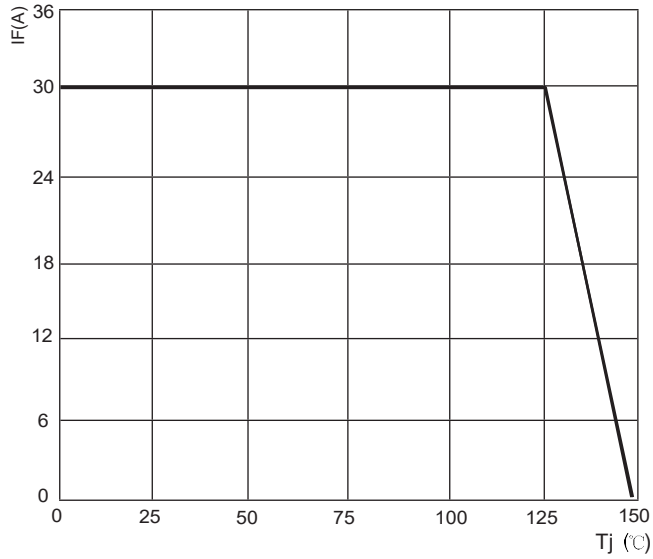
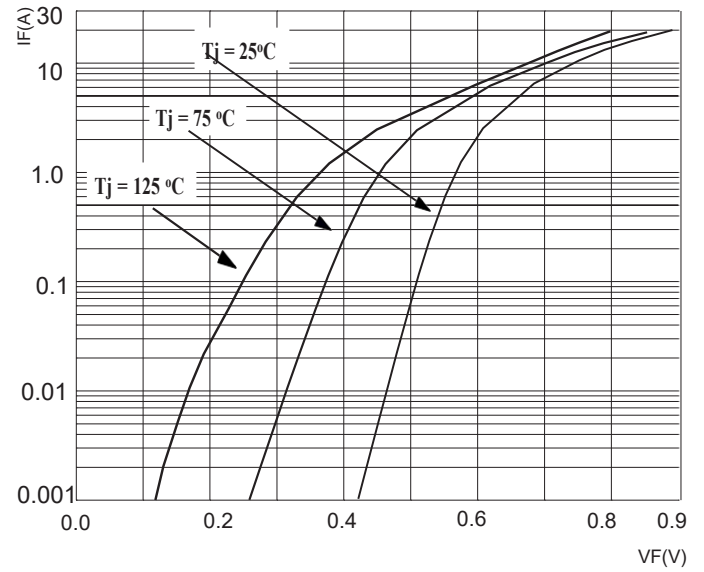
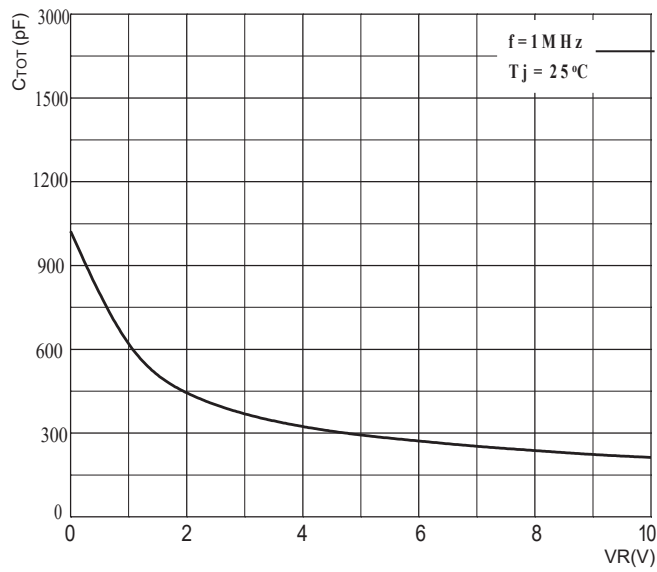
MAXIMUM RATINGS (T_a=25°C unless otherwise noted)

Symbol	Parameter	SBD		Unit
		30200CT	F30200CT	
V_{RRM}	Peak repetitive reverse voltage	200		V
V_{RWM}	Working peak reverse voltage			
V_R	DC blocking voltage			
$V_{R(RMS)}$	RMS reverse voltage	140		V
I_O	Average rectified output current	30		A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	200		A
$R_{\theta Jc}$	Thermal resistance from junction to case ,T _c =25°C	2.0	3.0	°C/W
$R_{\theta JA}$	Thermal resistance from junction to ambient	62.5		°C/W
T_j	Junction temperature	150		°C
T_{stg}	Storage temperature	-55~+150		°C

ELECTRICAL CHARACTERISTICS (T_a=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=0.1mA$	200			V
Reverse current	I_R	$V_R=200V$	T _j =25°C	5.0	100	uA
			T _j =125°C	5.0		mA
Forward voltage	V_F	$I_F=10A$	T _j =25°C	0.82		V
			T _j =125°C	0.71		V
		$I_F=15A$	T _j =25°C	0.87	0.95	V
			T _j =125°C	0.76		V

*Pulse test: pulse width ≤300μs, duty cycles ≤ 2.0%.

FIG.1: FORWARD CURRENT DERATING CURVE

FIG.2: TYPICAL FORWARD CHARACTERISTICS

FIG.3: TOTAL CAPACITANCE DERATING CURVE

FIG.4: TYPICAL REVERSE CHARACTERISTICS
